Vishay Semiconductors

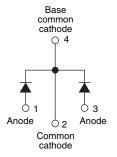
## High Performance Schottky Generation 5.0, 2 x 3 A

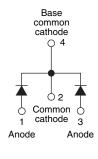






**D-PAK (TO-252AA)** 





VS-6CUT10-E

VS-6CWT10FN-E

PRODUCT SUMMARY					
Package	D-PAK (TO-252AA), I-PAK (TO-251AA)				
I <sub>F(AV)</sub>	2 x 3 A				
$V_{R}$	100 V				
V <sub>F</sub> at I <sub>F</sub>	0.63 V				
I <sub>RM</sub> max.	1 mA at 125 °C				
T <sub>J</sub> max.	175 °C				
Diode variation	Common cathode				
E <sub>AS</sub>	12 mJ				

#### **FEATURES**





- Very low forward voltage drop
- voly low low ward voltage arep
- Extremely low reverse leakage
- Optimized V<sub>F</sub> vs. I<sub>R</sub> trade off for high efficiency
- Increased ruggedness for reverse avalanche
- capabilityRBSOA available
- Negligible switching losses
- Submicron trench technology
- Compliant to RoHS Directive 2002/95/EC

#### **APPLICATIONS**

- · Specific for PV cells bypass diode
- High efficiency SMPS
- High frequency switching
- Output rectification
- Reverse battery protection
- Freewheeling
- DC/DC systems
- Increased power density systems

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS VALUES UNITS						
V <sub>RRM</sub>		100	V				
V <sub>F</sub>	3 A <sub>pk</sub> , T <sub>J</sub> = 125 °C (typical, per leg)	0.6	V				
T <sub>J</sub>	Range	- 55 to 175	°C				

VOLTAGE RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VS-6CUT10-E VS-6CWT10FN-E	UNITS
Maximum DC reverse voltage	$V_R$	T <sub>J</sub> = 25 °C	100	V



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ABSOLUTE MAXIMUM RATINGS									
PARAMETER		SYMBOL	TEST CONDITIONS		VALUES	UNITS			
Maximum average	per leg			FO 0/ duty avalant T 166 °C vactoravilar waveform		50 % duty cycle at T <sub>C</sub> = 166 °C, rectangular waveform		3	
forward current	per device	I <sub>F(AV)</sub>	AV) 50 % duty cycle at 1°C = 100 °C, rectangular wavelorm		6	А			
Maximum peak one cycle		I <sub>FSM</sub>	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated V <sub>RRM</sub> applied	440				
non-repetitive surge current per leg	10 ms sine or 6 ms rect. pulse		70						
Non-repetitive avalanche er	nergy per leg	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 4 A, L = 1.5 mH		12	mJ			
Repetitive avalanche currer	nt per leg	I <sub>AR</sub>	Limited by frequency of operation and time pulse duration so that $T_J < T_J max$ . $I_{AS}$ at $T_J max$ . as a function of time pulse. See fig. 8		I <sub>AS</sub> at T <sub>J</sub> max.	Α			

ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS		TYP.	MAX.	UNITS
Forward voltage drop per leg	V <sub>FM</sub> <sup>(1)</sup>	3 A	T <sub>J</sub> = 25 °C	0.720	0.79	V
		6 A		0.825	0.91	
		3 A	- T <sub>J</sub> = 125 °C	0.60	0.63	
		6 A		0.69	0.74	
Reverse leakage current per leg	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	V <sub>R</sub> = Rated V <sub>R</sub>	0.3	30	μA
		T <sub>J</sub> = 125 °C		0.3	1	mA
Junction capacitance per leg	C <sub>T</sub>	$V_R$ = 5 $V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		114	-	pF
Series inductance per leg	L <sub>S</sub>	Measured lead to lead 5 mm from package body		8.0	-	nH
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>		-	10 000	V/µs

#### Note

 $<sup>^{(1)}\,</sup>$  Pulse width < 300 µs, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL TEST CONDITIONS		VALUES	UNITS
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		- 55 to 175	°C
Maximum thermal resistance, junction to case per leg	D	DC operation	4.7	
Maximum thermal resistance, junction to case per device	R <sub>thJC</sub>		2.35	°C/W
Typical thermal resistance, case to heatsink	R <sub>thCS</sub>		0.3	
Approximate weight			0.3	g
			0.01	oz.
Madding daving		Case style I-PAK	6CUT10	
Marking device		Case style D-PAK	6CWT	10FN

#### www.vishay.com

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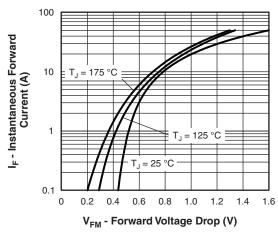


Fig. 1 - Maximum Forward Voltage Drop Characteristics

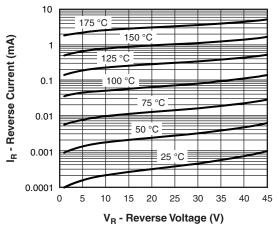


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

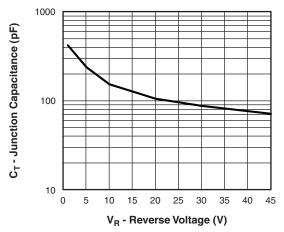


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

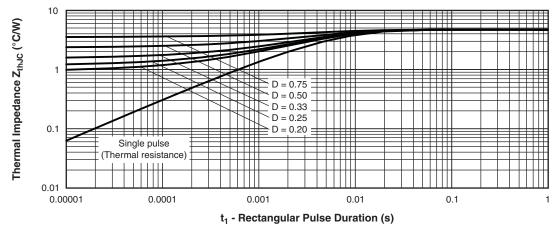
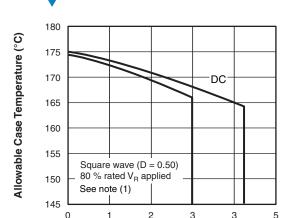


Fig. 4 - Maximum Thermal Impedance  $Z_{thJC}$  Characteristics



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I<sub>F(AV)</sub> - Average Forward Current (A)
Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

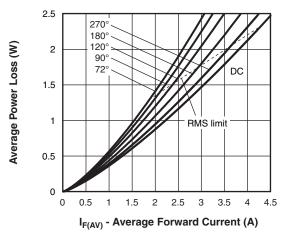


Fig. 6 - Forward Power Loss Characteristics

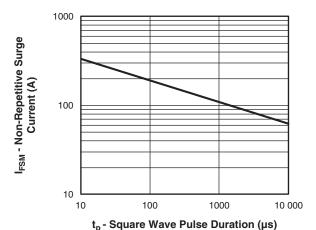


Fig. 7 - Maximum Non-Repetitive Surge Current

#### Note

 $^{(1)}$  Formula used: T<sub>C</sub> = T<sub>J</sub> - (Pd + Pd<sub>REV</sub>) x R<sub>th,JC</sub>; Pd = Forward power loss = I<sub>F(AV)</sub> x V<sub>FM</sub> at (I<sub>F(AV)</sub>/D) (see fig. 6); Pd<sub>REV</sub> = Inverse power loss = V<sub>R1</sub> x I<sub>R</sub> (1 - D); I<sub>R</sub> at V<sub>R1</sub> = 80 % rated V<sub>R</sub>

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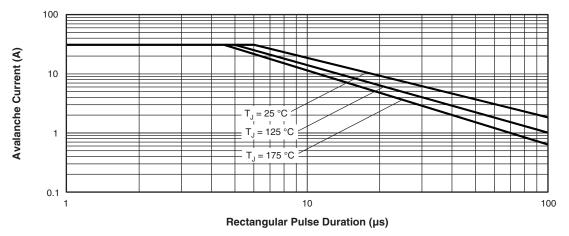


Fig. 8 - Reverse Bias Safe Operating Area (Avalanche Current vs. Rectangular Pulse Duration)

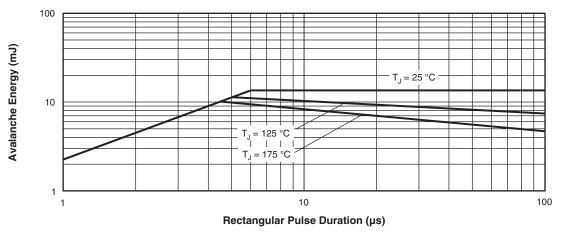
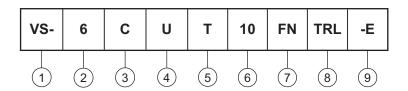


Fig. 9 - Reverse Bias Safe Operating Area (Avalanche Energy vs. Rectangular Pulse Duration)

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### **ORDERING INFORMATION TABLE**

#### **Device code**



1 - Vishay Semiconductors product

2 - Current rating (2 x 3 A)

3 - Circuit configuration:

C = Common cathode

4 - Package:

U = I-PAK

W = D-PAK

5 - T = Trench

6 - Voltage rating (10 = 100 V)

7 - TO-252AA (D-PAK)

8 - D-PAK, I-PAK:

None = Tube (75 pieces)

D-PAK only:

• TR = Tape and reel

• TRL = Tape and reel (left oriented)

• TRR = Tape and reel (right oriented)

9 - Environmental digit:

-E = RoHS compliant and terminations lead (Pb)-free

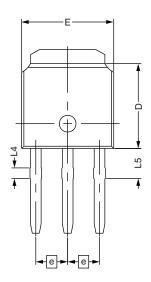
LINKS TO RELATED DOCUMENTS				
Dimensions	I-PAK (TO-251AA)	www.vishay.com/doc?95024		
Dimensions	D-PAK (TO-252AA)	www.vishay.com/doc?95448		
Part marking information	I-PAK-E (TO-251AA)	www.vishay.com/doc?95097		
	D-PAK-E (TO-252AA)	www.vishay.com/doc?95176		

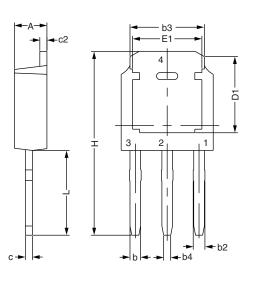


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### I-PAK - S

### **DIMENSIONS FOR I-PAK - S** in millimeters





SYMBOL	DIMENSIONAL REQUIREMENTS			
STMBOL	MIN.	NOM.	MAX.	
E	6.40	6.60	6.70	
L	3.98	4.13	4.28	
L4	0.66	0.76	0.86	
L5	1.96	2.16	2.36	
D	6.00	6.10	6.20	
Н	11.05	11.25	11.45	
b	0.64	0.76	0.88	
b2	0.77	0.84	1.14	
b3	5.21	5.34	5.46	
b4	0.41	0.51	0.61	
е	2.286 BSC			
Α	2.20	2.30	2.38	
С	0.40 0.50		0.60	
c2	0.40 0.50 0.		0.60	
D1	5.30		-	
E1	4.40		-	

### **Legal Disclaimer Notice**



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